

CSD25481F4 20 V P-Channel FemtoFET™ MOSFET

1 Features

- Ultra-Low On Resistance
- Ultra-Low Q_g and Q_{gd}
- High Operating Drain Current
- Ultra-Small Footprint (0402 Case Size)
 - 1 mm × 0.6 mm
- Ultra-Low Profile
 - 0.35 mm Max Height
- Integrated ESD Protection Diode
 - Rated >4 kV HBM
 - Rated >2 kV CDM
- Lead and Halogen Free
- RoHS Compliant

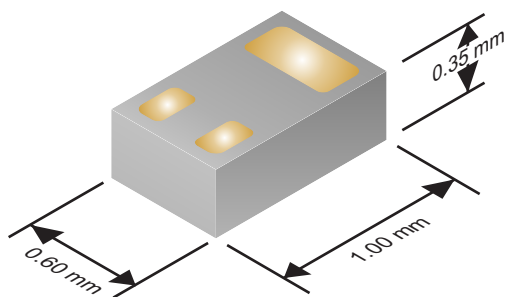
2 Applications

- Optimized for Load Switch Applications
- Optimized for General Purpose Switching Applications
- Battery Applications
- Handheld and Mobile Applications

3 Description

This 90 mΩ, 20 V P-Channel FemtoFET™ MOSFET is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing at least a 60% reduction in footprint size.

Typical Part Dimensions



Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	-20		V
Q_g	Gate Charge Total (-4.5 V)	913		pC
Q_{gd}	Gate Charge Gate-to-Drain	153		pC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = -1.8\text{ V}$	395	mΩ
		$V_{GS} = -2.5\text{ V}$	145	mΩ
		$V_{GS} = -4.5\text{ V}$	90	mΩ
$V_{GS(th)}$	Threshold Voltage	-0.95		V

Ordering Information⁽¹⁾

Device	Qty	Media	Package	Ship
CSD25481F4	3000	7-Inch Reel	Femto(0402) 1.0 mm × 0.6 mm	Tape and Reel
CSD25481F4T	250	7-Inch Reel	Land Grid Array (LGA)	

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	-20	V
V_{GS}	Gate-to-Source Voltage	-12	V
I_D	Continuous Drain Current ⁽¹⁾	-2.5	A
I_{DM}	Pulsed Drain Current ⁽²⁾	-13.1	A
I_G	Continuous Gate Clamp Current	-35	mA
	Pulsed Gate Clamp Current ⁽²⁾	-350	
P_D	Power Dissipation ⁽¹⁾	500	mW
$V_{(ESD)}$	Human Body Model (HBM)	4	kV
	Charged Device Model (CDM)	2	kV
T_J, T_{stg}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$

(1) Typical $R_{\theta JA} = 90^\circ\text{C/W}$ on 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu pad on a 0.06 inch (1.52 mm) thick FR4 PCB.

(2) Pulse duration $\leq 100\ \mu\text{s}$, duty cycle $\leq 1\%$.

Top View

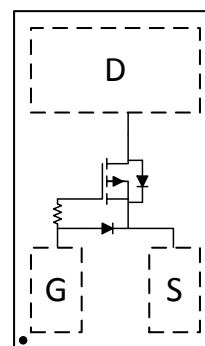


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (October 2014) to Revision E	Page
• Changed the Pulsed Drain Current value From: –10 A To: –13.1 A in the <i>Absolute Maximum Ratings</i> table	1
• Changed Note 1 From: Typical $R_{\theta JA} = 85^{\circ}\text{C/W}$ To: Typical $R_{\theta JA} = 90^{\circ}\text{C/W}$	1
• Changed Note 2 From: Pulse duration $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$ To: Pulse duration $\leq 100\ \mu\text{s}$, duty cycle $\leq 1\%$	1
• Changed the typical $R_{\theta JA}$ values in the <i>Thermal Information</i> table	3
• Updated Figure 1	4
• Updated Figure 10 with newly measured data.	5
• Added Community Resources	7
• Updated all mechanical drawings, increased the size of the pads in the Recommended Stencil Pattern section.	8
Changes from Revision C (February 2014) to Revision D	Page
• Corrected timing V_{DS} to read –10 V.	3
Changes from Revision B (February 2013) to Revision C	Page
• Corrected capacitance units to read pF in Figure 5	5
Changes from Revision A (December 2013) to Revision B	Page
• Updated lead and halogen free in features.	1
• Added I_G parameter.	1
• Lowered I_{DSS} limit.	3
• Lowered I_{GSS} limit.	3
Changes from Original (September 2013) to Revision A	Page
• Took out jumbo reel info and added small reel info.	1
• Removed UIS graph.	5

5 Specifications

5.1 Electrical Characteristics

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
B _V DSS	Drain-to-Source Voltage	V _{GS} = 0 V, I _{DS} = -250 μA	-20			V
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0 V, V _{DS} = -16 V			-100	nA
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS} = -12 V			-50	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	V _{DS} = V _{GS} , I _{DS} = -250 μA	-0.7	-0.95	-1.2	V
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = -1.8 V, I _{DS} = -0.1 A		395	800	mΩ
		V _{GS} = -2.5 V, I _{DS} = -0.5 A		145	174	mΩ
		V _{GS} = -4.5 V, I _{DS} = -0.5 A		90	105	mΩ
		V _{GS} = -8 V, I _{DS} = -0.5 A		75	88	mΩ
g _{fs}	Transconductance	V _{DS} = -10 V, I _{DS} = -0.5 A		3.3		S
DYNAMIC CHARACTERISTICS						
C _{iss}	Input Capacitance	V _{GS} = 0 V, V _{DS} = -10 V, f = 1 MHz		189		pF
C _{oss}	Output Capacitance			78		pF
C _{rss}	Reverse Transfer Capacitance			5.5		pF
R _G	Series Gate Resistance			20		Ω
Q _g	Gate Charge Total (4.5 V)	V _{DS} = -10 V, I _{DS} = -0.5 A		913		pC
Q _{gd}	Gate Charge Gate-to-Drain			153		pC
Q _{gs}	Gate Charge Gate-to-Source			240		pC
Q _{g(th)}	Gate Charge at V _{th}			116		pC
Q _{oss}	Output Charge		V _{DS} = -10 V, V _{GS} = 0 V		1030	
t _{d(on)}	Turn On Delay Time	V _{DS} = -10 V, V _{GS} = -4.5 V, I _{DS} = -0.5 A, R _G = 2 Ω		4.1		ns
t _r	Rise Time			3.6		ns
t _{d(off)}	Turn Off Delay Time			16.9		ns
t _f	Fall Time			6.7		ns
DIODE CHARACTERISTICS						
V _{SD}	Diode Forward Voltage	I _{SD} = -0.5 A, V _{GS} = 0 V		-0.75		V
Q _{rr}	Reverse Recovery Charge	V _{DS} = -10 V, I _F = -0.5 A, di/dt = 100 A/μs		1010		pC
t _{rr}	Reverse Recovery Time			7.5		ns

5.2 Thermal Information

(T_A = 25°C unless otherwise stated)

THERMAL METRIC		TYPICAL VALUES	UNIT
R _{θJA}	Junction-to-Ambient Thermal Resistance ⁽¹⁾	90	°C/W
	Junction-to-Ambient Thermal Resistance ⁽²⁾	250	

(1) Device mounted on FR4 material with 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu.

(2) Device mounted on FR4 material with minimum Cu mounting area.

5.3 Typical MOSFET Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise stated)

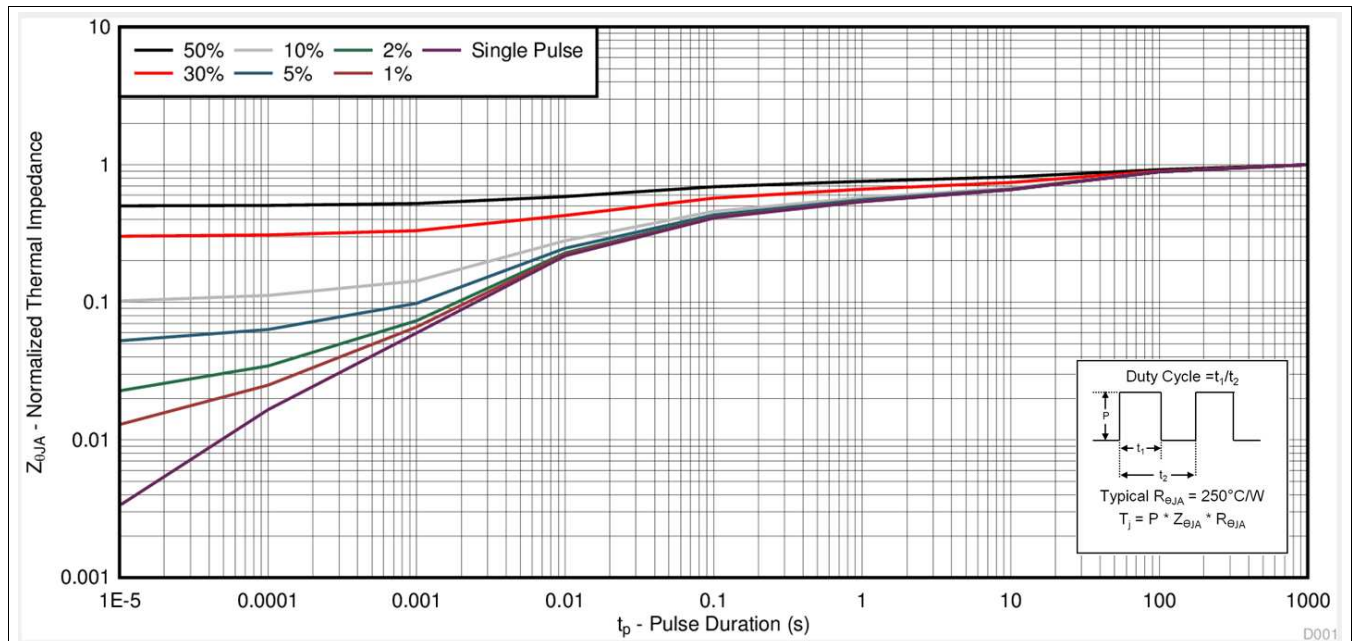


Figure 1. Transient Thermal Impedance

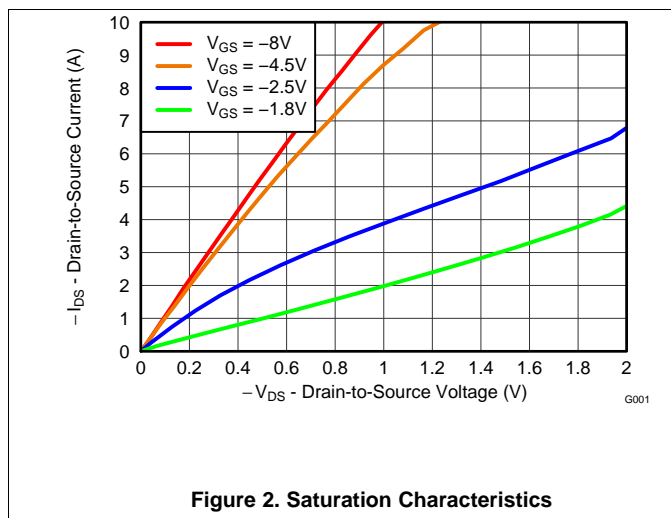


Figure 2. Saturation Characteristics

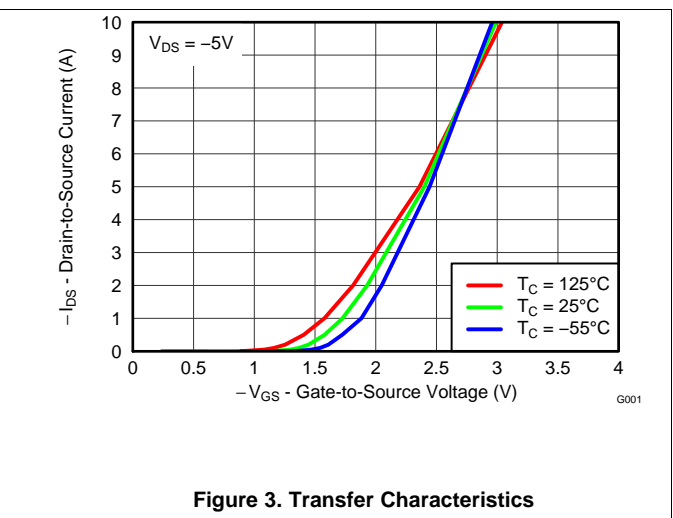
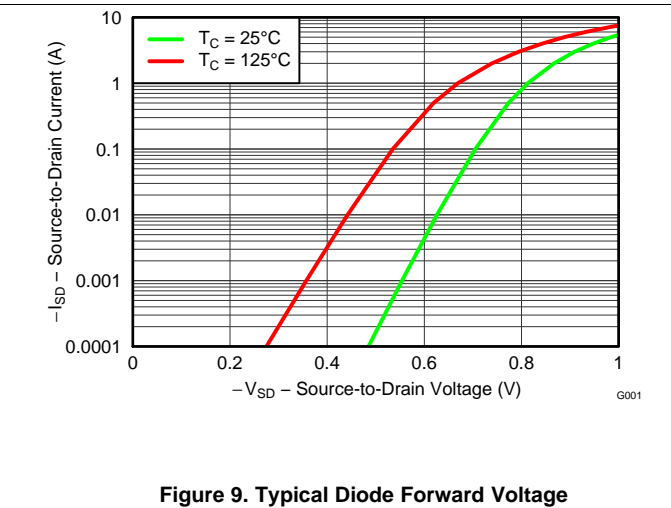
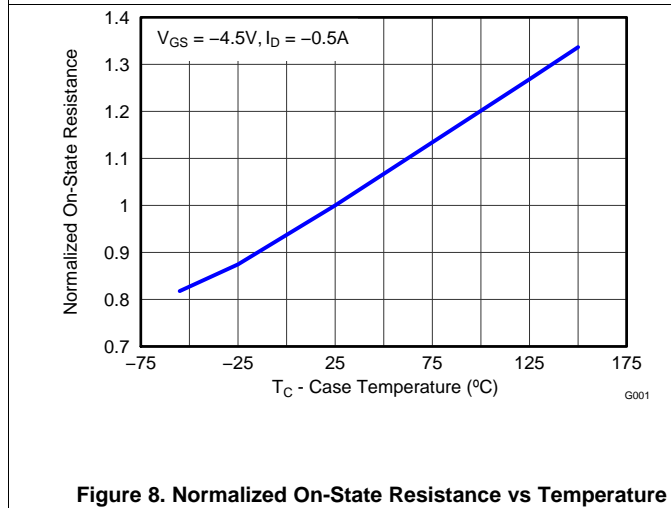
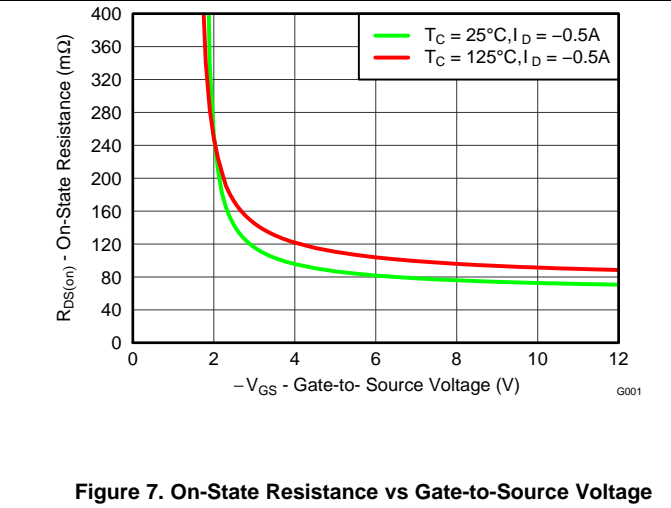
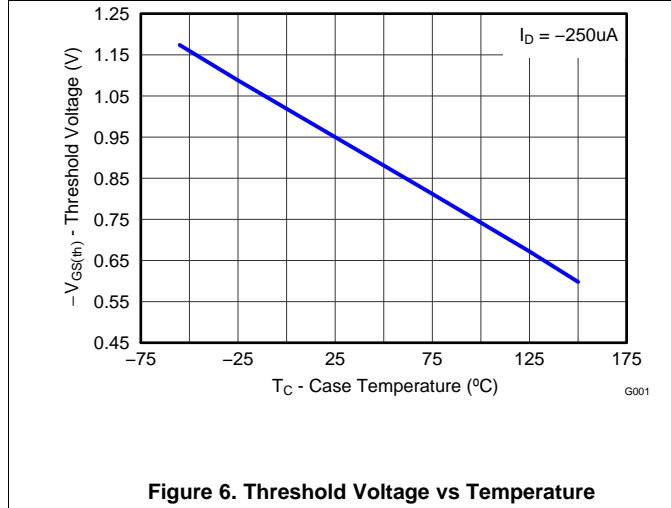
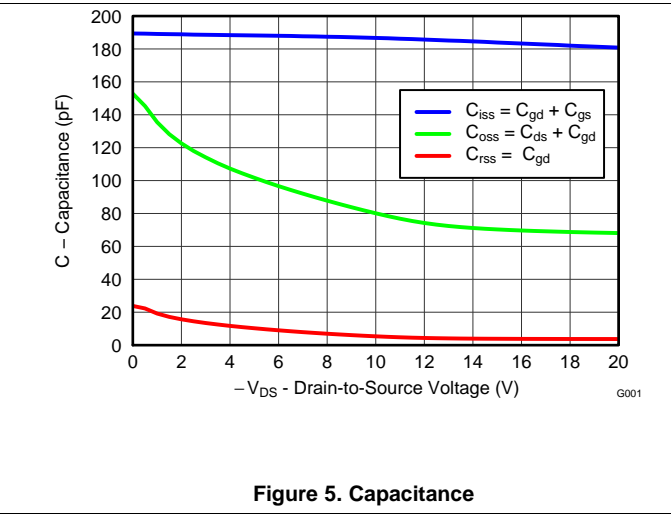
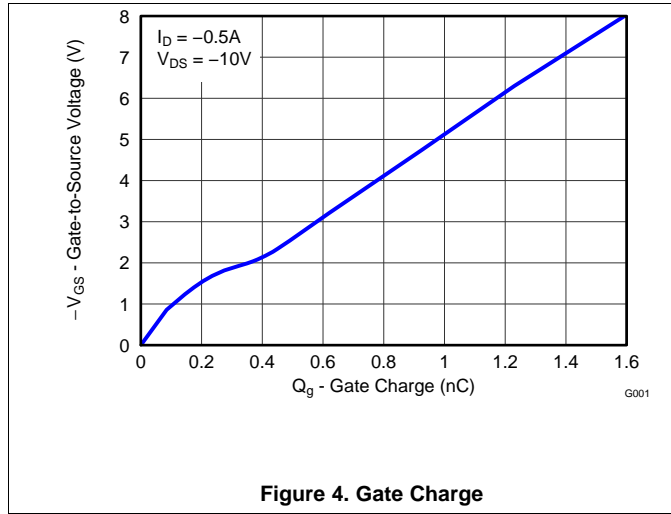


Figure 3. Transfer Characteristics

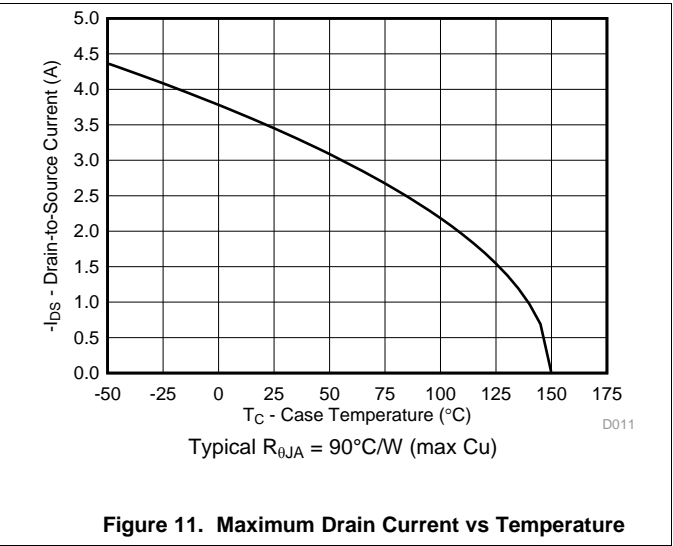
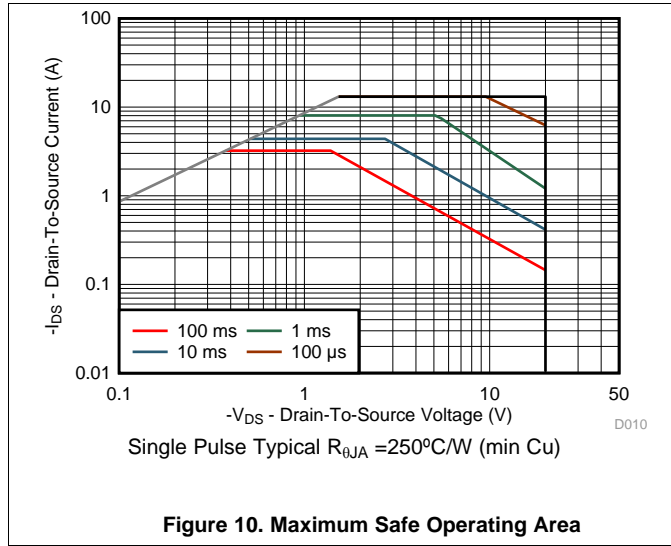
Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)



Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)



6 Device and Documentation Support

6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.2 Trademarks

FemtoFET, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.4 Glossary

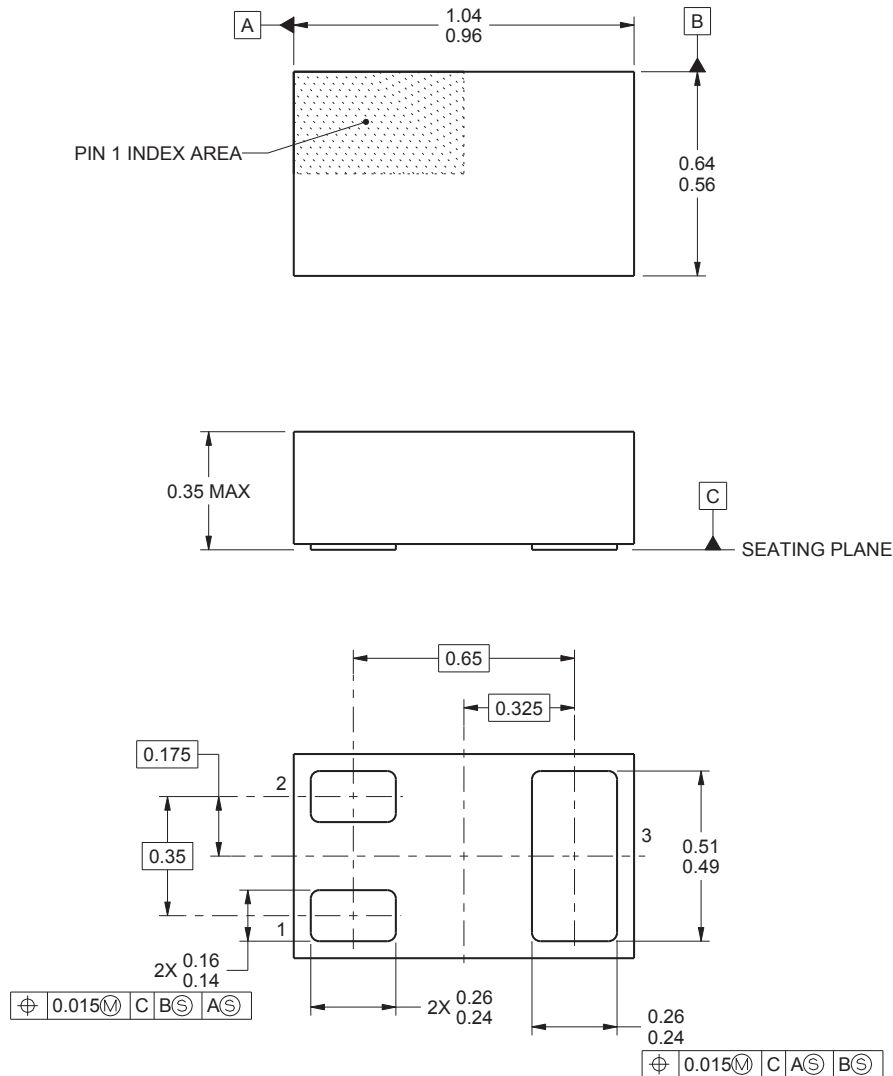
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Mechanical Dimensions

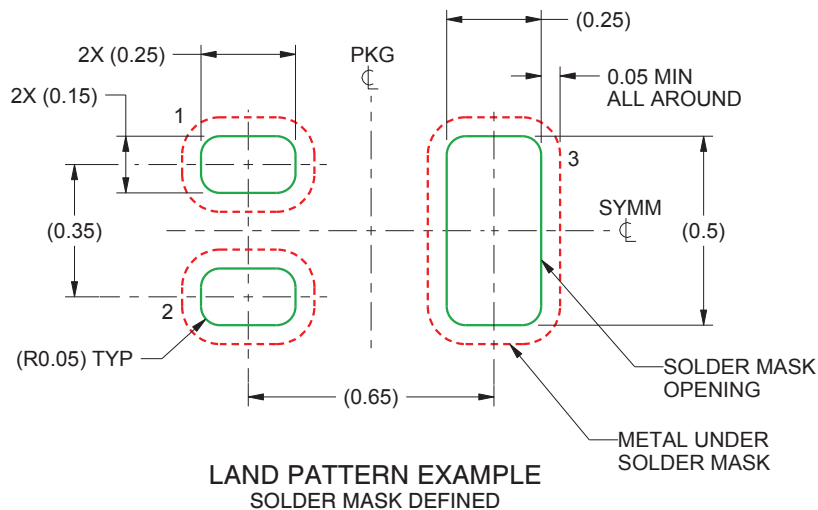


- (1) All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- (2) This drawing is subject to change without notice.
- (3) This package is a Pb-free bump design. Bump finish may vary. To determine the exact finish, refer to the device data sheet or contact a local TI representative.

Table 1. Pin Configuration

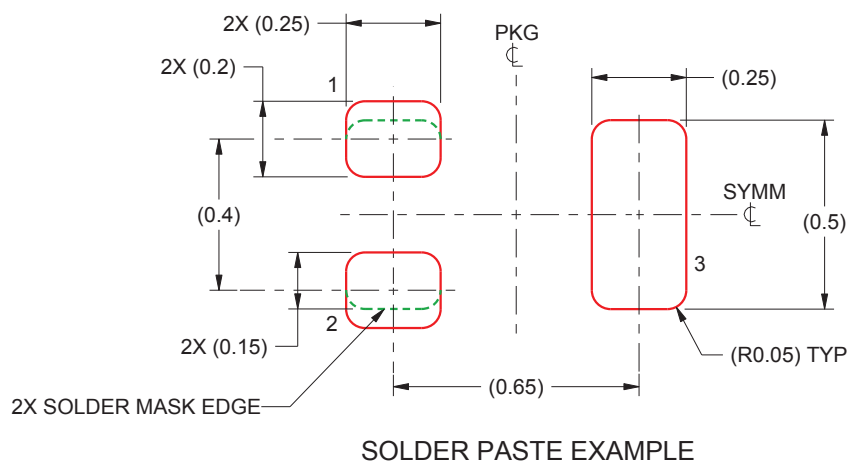
Position	Designation
Pin 1	Gate
Pin 2	Source
Pin 3	Drain

7.2 Recommended Minimum PCB Layout



- (1) All dimensions are in millimeters.
- (2) For more information, see [QFN/SON PCB Attachment](#) (SLUA271).

7.3 Recommended Stencil Pattern



- (1) All dimensions are in millimeters.
- (2) Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD25481F4	ACTIVE	PICOSTAR	YJC	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	CS	Samples
CSD25481F4T	ACTIVE	PICOSTAR	YJC	3	250	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	CS	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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